

Power Electronics ELEC-E8412 Power Electronics, 5 ECTS

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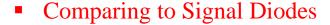
Course Objectives

At the end of this chapter, you will be able to:

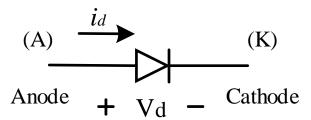
- Describe the operation of different Power Electronic Components (Diode, Thyristor (SCR), MOSTFET, and IGBT)
- Find the right component based on the application

1. Diodes:

A diode is the simplest electronic switch. It is uncontrollable in that the ON and OFF conditions are determined by voltages and currents in the circuit.



- More complicated structure
- Much higher V and I ratings
- Used in power processing
 - Lower frequency response
 - Higher on-state voltage (forward voltage, VF)



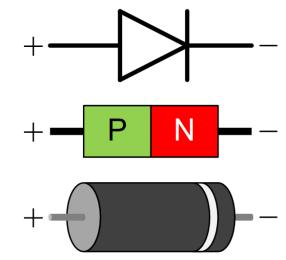


Figure 2-1: schematic diagram of an Ideal Diode.

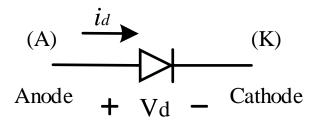


Figure 2-1: schematic diagram of an Ideal Diode.

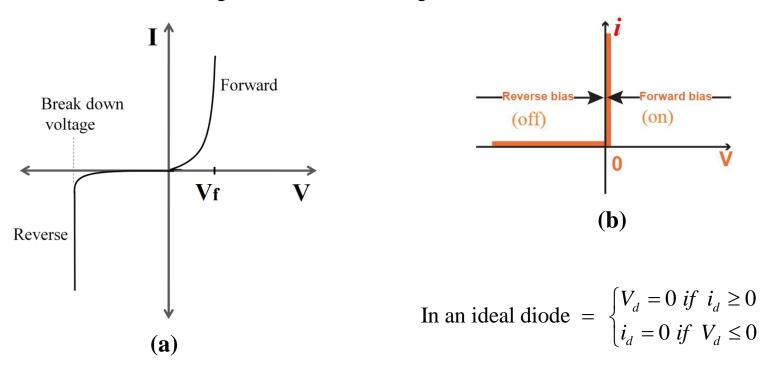


Figure 2-2: The current-voltage characteristic curve of: (a) non-ideal (real), (b) ideal diodes.

2. Thyristor or SCR (Silicon Controlled Rectifier):

Thyristors are electronic switches used in some power electronic circuits where control of switch turn-on is required.

- Developed in 1960s
- Switched on by a short injecting gate current pulse
 - Firing or Triggering (Triggering means sending an impulse of current into the gate)
- Switched off when reverse biased
- Ratings up to 5kV and 4000A
 - Very high power applications
- Slow response
 - fs < 1kHz

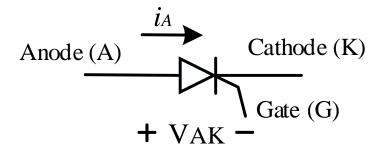


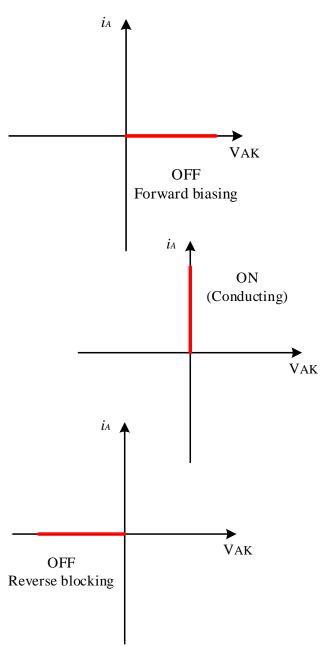
Figure 2-4: schematic diagram of Thyristor.



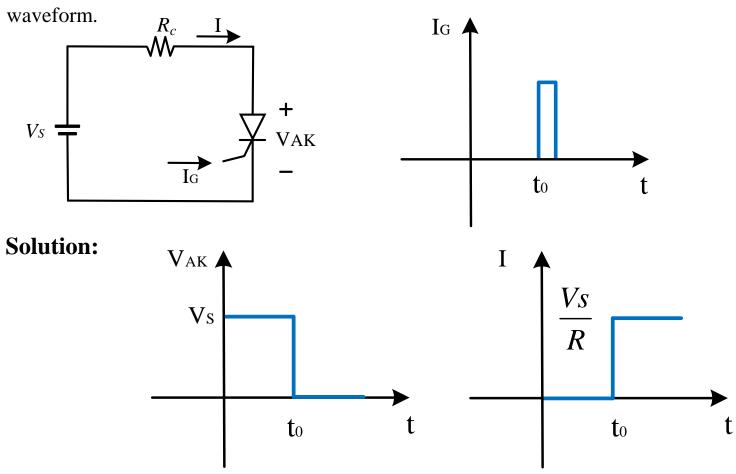
• If we have not sent any signal to the gate (not triggered), Thyristor will be off and the current is zero. This region is called as forward biasing.

• If we send a signal to the gate (trigger), Thyristor will be ON and the voltage will be zero.

- If we do not apply any gate signal it can also block negative voltage.
- ❖ A Thyristor is going turn off when it's current is back to zero.

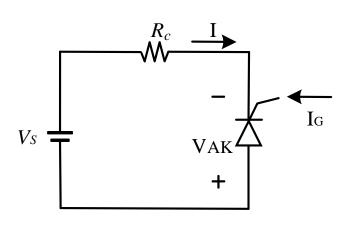


Example: At the following circuit, the gate was triggered at to. Draw the voltage and current



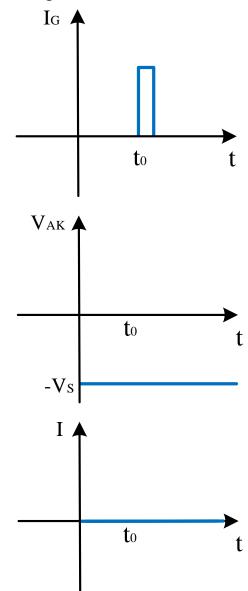
❖ As the source is a DC source, this will continue for ever without to have possibility to turn it off. In other word, if the current conducting positive, the conduction will be continued for ever unless the situation change and current comes back to the zero value.

Example: At the following circuit, the gate was triggered at to. Draw the voltage and current waveform.



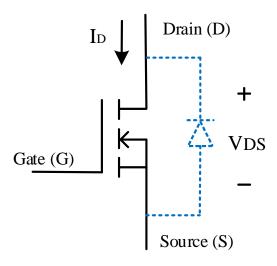
Solution:

- ❖ Before t₀, Thyristor is off, and it is blocking some negative voltage. As it is in reverse blocking mode, it never turned on, therefore, VAK will be always -Vs. In addition, the current will be always equal to zero.
- ❖ A Thyristor is turned on by applying a gate current while it is in the forward blocking state. Once Thyristor is turned on, the device continues to conduct even if the gating signal is removed. The Thyristor will continue to conduct as long as the current remains positive.



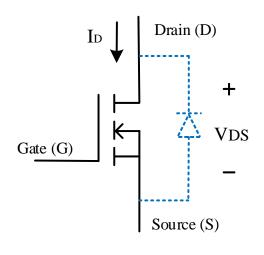
3. Power MOSTFET:

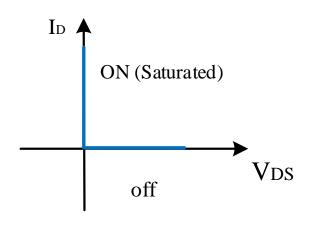
- Metal Oxide Silicon Field Effect Transistor
- Developed in early 1980s
- Controlled by gate-to-source voltage (VGS)
 - Gate Signal, 10V to 18V, typically 15V
- Ratings up to 1000V and 2000A
 - High current low voltage applications
 - Switched-mode power supply (SMPS), battery chargers
- Very fast response
 - fs < 1MHz, higher for soft-switching
- Bidirectional and resistive conduction characteristics



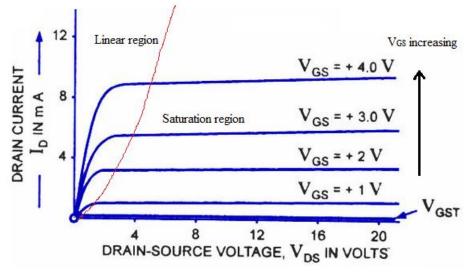


Schematic diagram of MOSTFET





Ideal MOSTFET



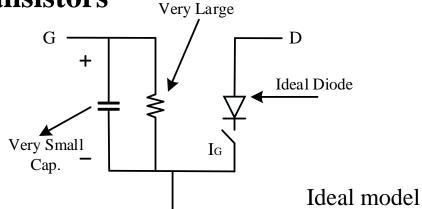
Real MOSTFET

VT depends on what kind of MOSTFET is used, and its value normally appeared in datasheets. The maximum value of VT is 5V.

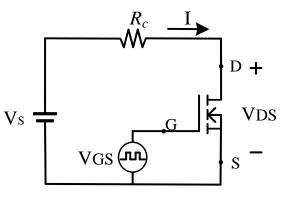
 $\begin{cases} \text{if} \quad V_{GS} > V_T \quad \Rightarrow \quad \text{Switch is ON} \quad \Rightarrow \quad V_{DS} = 0 \\ \text{if} \quad V_{GS} < V_T \quad \Rightarrow \quad \text{Switch is off} \quad \Rightarrow \quad I_D = 0 \end{cases}$

Circuit Model of MOSTFETs:

- The value of capacitor and resistor is mentioned in datasheet of MOSTFET.
- Switch is ON/OFF based on the logic mentioned in pervious page.

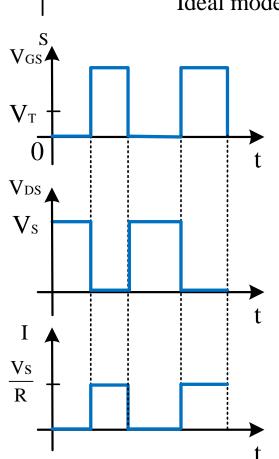


Example: Find the V_{DS} and the current of MOSTFET.



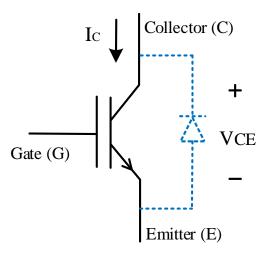
Solution: At t= 0 sec V_{GS}< V_T, therefore, switch is off and there V_{DS} is no current passing through the switch.

As soon as a voltage applied to the GS reach bigger than V_T, the device will be turned on. Therefore, it behaves like short circuit.



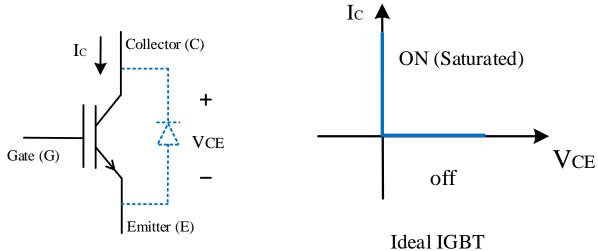
4. IGBT:

- Insulated Gate Bipolar Transistor
- Developed in late 1980s
- Controlled by gate-to-emitter voltage (VGE)
 - Same as MOSFET
- Ratings up to 3500V and 2000A
 - Medium to high power applications up to 200kW
 - Popular in Motor drives
- On-state voltage 1.7V to 3V
- Fast response
 - Typically fs< 40kHz, faster for some models

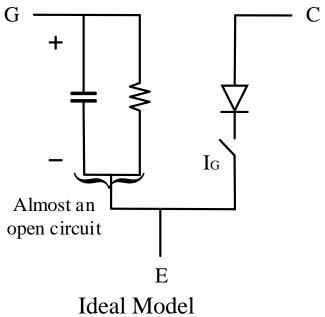


Schematic diagram of IGBT





$$\begin{cases} \text{if} \quad V_{\text{GE}} > V_{\text{T}} \quad \Rightarrow \quad \text{Switch is ON} \quad \Rightarrow \quad V_{\text{CE}} = 0 \\ \text{if} \quad V_{\text{GE}} < V_{\text{T}} \quad \Rightarrow \quad \text{Switch is off} \quad \Rightarrow \quad I_{\text{C}} = 0 \end{cases}$$



❖ From our point of view power MOSTFETs and IGBTs are equal, however here are the differences.

| | Switching Frequency | Maximum Voltage Rating (Vs) | Maximum Current rating |
|---------|---------------------|-----------------------------|------------------------|
| MOSTFET | Very High | 1 kv | 150 A |
| IGBT | High | 5 kv (or more) | 2 kA |

❖ Power Switches all together

| | Diode | SCR | MOSTFET | IGBT |
|------------------------------------|-------|----------|----------|----------|
| Controlled turn on | Χ | / | | / |
| Controlled turn off | X | X | / | / |
| Continuous gate signal requirement | _ | Χ | | / |
| Bidirectional current capability | Χ | Χ | ? | X |

Questions and comments are most welcome!

